

### FEATURES

- High Output Power: 31.0dBm (typ.)
- High Linear Gain: 20dB (typ.)
- Low In/Out VSWR
- Integrated Output Power Monitor
- Impedance Matched  $Z_{in}/Z_{out} = 50\Omega$
- Small Hermetic Metal-Ceramic Package (VF)



### DESCRIPTION

The FMM5007VF is a MMIC amplifier designed for VSAT applications as a driver or output stage in the 14.0 to 14.5 GHz band.

Fujitsu's stringent Quality Assurance Program assures the highest reliability and consistent performance.

### ABSOLUTE MAXIMUM RATINGS (Ambient Temperature $T_a=25^\circ\text{C}$ )

Item	Symbol	Rating	Unit
DC Input Voltage	$V_{DD}$	12	V
DC Input Voltage	$V_{GG}$	-7	V
Input Power	$P_{in}$	20	dBm
Storage Temperature	$T_{stg}$	-55 to +125	$^\circ\text{C}$
Operating Case Temperature	$T_{op}$	-40 to +85	$^\circ\text{C}$

### ELECTRICAL CHARACTERISTICS (Ambient Temperature $T_a=25^\circ\text{C}$ )

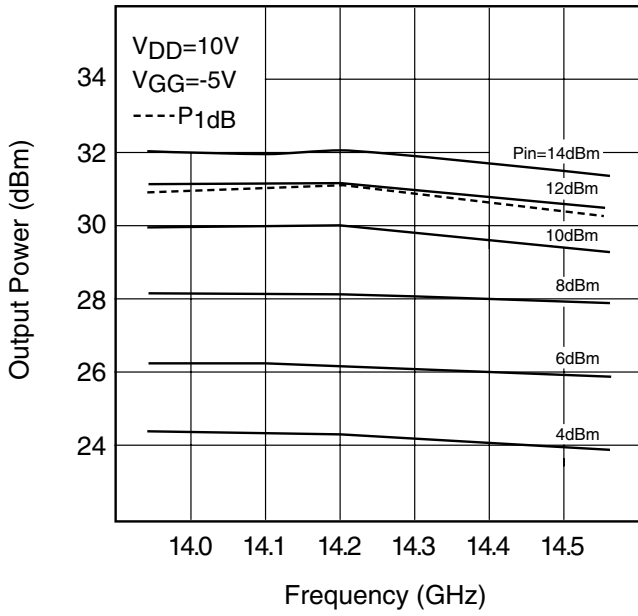
Item	Symbol	Test Conditions	Limit			Unit
			Min.	Typ.	Max.	
Frequency Range	f		14.0	-	14.5	GHz
Output Power at 1dB G.C.P.	$P_{1dB}$	$V_{DD} = 10V$ $V_{GG} = -5V$ $f = 14.0 \text{ to } 14.5 \text{ GHz}$	30.0	31.0	-	dBm
Linear Gain	G		18.0	20.0	-	dB
Gain Flatness	$\Delta G$		-	1.0	1.5	dB
Input VSWR	$VSWR_i$		-	2:1	2.3:1	-
Output VSWR	$VSWR_o$		-	2.3:1	3:1	-
Power Monitor	$V_{mon}$	$P_{out} = 30\text{dBm}$	-	3.5	-	V
DC Input Current	$I_{DD}$	$V_{DD} = 10V$ $V_{GG} = -5V$	-	1000	1200	mA
DC Input Current	$I_{GG}$		-	15	20	mA

CASE STYLE: VF

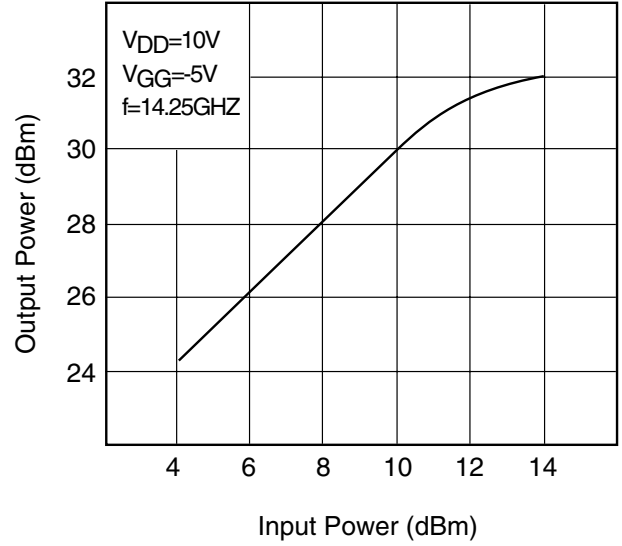
# FMM5007VF

GaAs MMIC

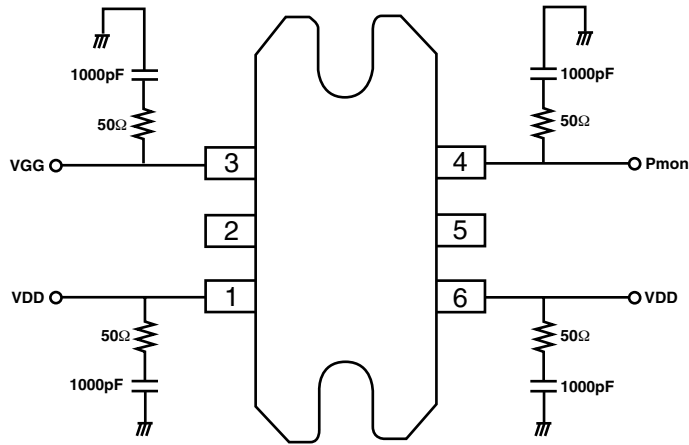
### OUTPUT POWER vs. FREQUENCY

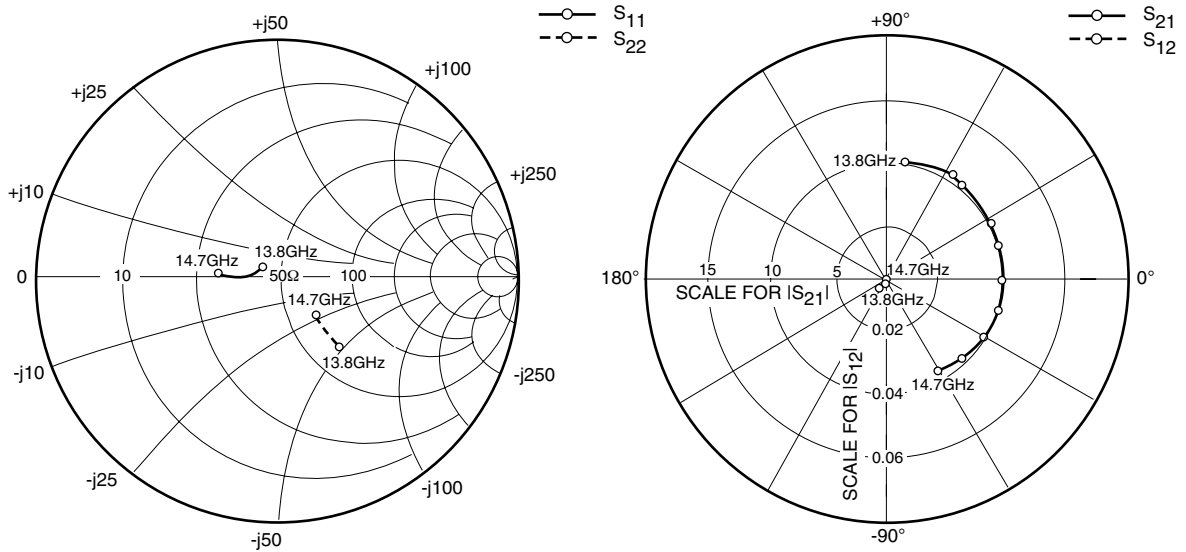


### OUTPUT POWER vs. INPUT POWER



### Recommended Bias Circuit

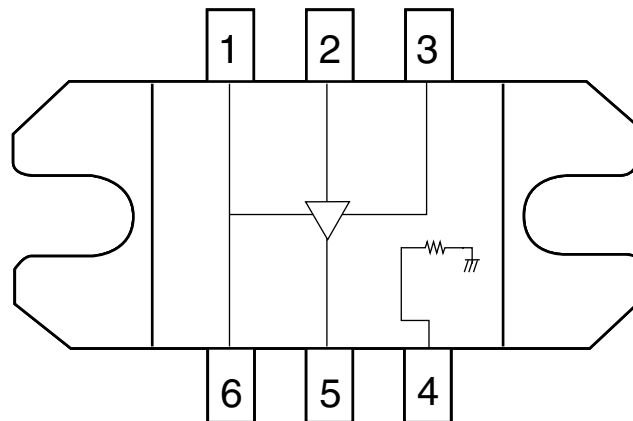




**S-PARAMETERS**  
 $V_{DD} = 10V, V_{GG} = -5V$

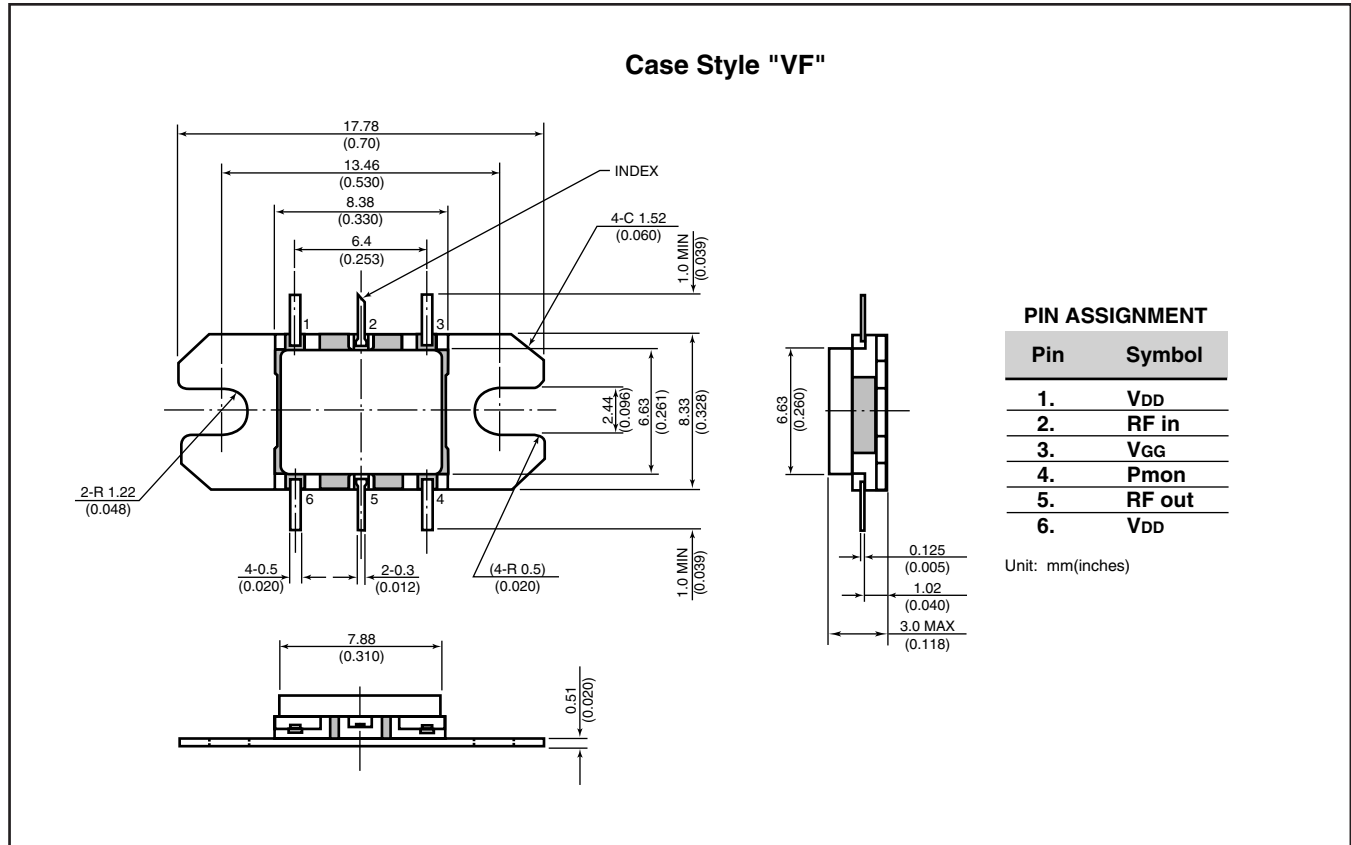
FREQUENCY (MHZ)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
13800	.081	150.5	10.412	78.2	.004	-109.4	.400	-45.0
13900	.066	144.4	10.869	55.9	.004	-165.3	.377	-44.4
14000	.053	141.5	10.443	46.5	.009	-163.0	.359	-44.8
14100	.052	152.1	10.511	26.7	.008	-128.8	.328	-43.6
14200	.052	163.7	10.387	14.9	.005	171.8	.316	-45.2
14300	.069	177.3	10.078	-2.6	.005	-123.7	.299	-43.5
14400	.090	178.7	9.953	-15.6	.004	-90.4	.281	-43.6
14500	.119	-178.1	9.496	-30.3	.006	-160.1	.259	-42.8
14600	.161	178.0	9.486	-45.6	.001	-164.1	.232	-42.5
14700	.201	173.7	8.887	-59.6	.001	-104.3	.213	-37.6

### Pin Configuration



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GaAs MMIC



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- Do not alter the form of this product into a gas, powder, or liquid through burning, crushing, or chemical processing as these by-products are dangerous to the human body if inhaled, ingested, or swallowed.
- Observe government laws and company regulations when discarding this product. This product must be discarded in accordance with methods specified by applicable hazardous waste procedures.

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